FAIRCHILD

SEMICONDUCTOR

MM74HCT04 Hex Inverter

General Description

The MM74HCT04 is a logic function fabricated by using advanced silicon-gate CMOS technology which provides the inherent benefits of CMOS - low quiescent power and wide power supply range. This device is input and output characteristic as well as pin-out compatible with standard 74LS logic families. The MM74HCT04, triple buffered, hex inverters, features low power dissipation and fast switching times. All inputs are protected from static discharge by internal diodes to V_{CC} and ground.

MM74HCT devices are intended to interface between TTL and NMOS components and standard CMOS devices.

These parts are also plug-in replacements for LS-TTL devices and can be used to reduce power consumption in existing designs.

February 1984

Revised February 1999

Features

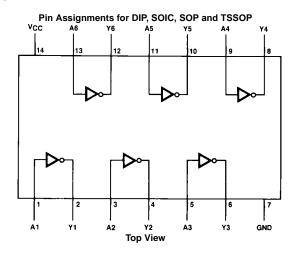
- TTL, LS pin-out and threshold compatible
- Fast switching: t_{PLH}, t_{PHL}=12 ns (typ)
- Low power: 10 µW at DC, 3.7 mW at 5 MHz
- High fanout: ≥ 10 LS loads
- Inverting, triple buffered

Ordering Code:

Order Number	Package Number	Package Description			
MM74HCT04M	M14A	14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150" Narrow			
MM74HCT04SJ	M14D	14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide			
MM74HCT04MTC	MTC14	14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide			
MM74HCT04N	N14A	14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide			

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Connection Diagram



www.fairchildsemi.com

Absolute Maximum Ratings(Note 1) (Note 2)

`	,	
	Supply Voltage (V _{CC})	-0.5 to +7.0V
	DC Input Voltage (V _{IN})	-1.5 to $V_{CC}{+}1.5V$
	DC Output Voltage (V _{OUT})	–0.5 to V_{CC} +0.5V
	Clamp Diode Current (I _{IK} , I _{OK})	±20 mA
	DC Output Current, per pin (I _{OUT})	±25 mA
	DC V_{CC} or GND Current, per pin (I_{CC})	±50 mA
	Storage Temperature Range (T _{STG})	$-65^{\circ}C$ to $+150^{\circ}C$
	Power Dissipation (P _D)	
	(Note 3)	600 mW
	S.O. Package only	500 mW
	Lead Temperature (TL)	
	(Soldering 10 seconds)	260°C

Recommended Operating Conditions

	Min	Max	Units			
Supply Voltage (V _{CC})	4.5	5.5	V			
DC Input or Output Voltage						
(V _{IN} , V _{OUT})	0	V_{CC}	V			
Operating Temperature Range (T_A)	-40	+85	°C			
Input Rise or Fall Times						
(t _r , t _f)		500	ns			
Note 1: Absolute Maximum Ratings are those values beyond which damage to the device may occur.						
Note 2: Unless otherwise specified all voltages are referenced to ground						

Note 2: Unless otherwise specified all voltages are referenced to ground. Note 3: Power Dissipation temperature derating — plastic "N" package: – 12 mW/°C from 65°C to 85°C.

DC Electrical Characteristics

$V_{CC}\,{=}\,5V\,{\pm}10\%$ (unless otherwise specified)

Cumb al	Parameter	Conditions	T _A =	25°C	$T_A = -40$ to $85^{\circ}C$	$T_A = -55$ to $125^{\circ}C$	Units
Symbol		Conditions	Тур		Guaranteed	Units	
VIH	Minimum HIGH Level			2.0	2.0	2.0	V
	Input Voltage						
V _{IL}	Maximum LOW Level			0.8	0.8	0.8	V
	Input Voltage						
V _{OH}	Minimum HIGH Level	$V_{IN} = V_{IL}$					
	Output Voltage	$ I_{OUT} = 20 \ \mu A$	V _{CC}	$V_{CC} - 0.1$	$V_{CC} - 0.1$	V _{CC} - 0.1	V
		$ I_{OUT} = 4.0 \text{ mA}, V_{CC} = 4.5 \text{V}$	4.2	3.98	3.84	3.7	V
		$ I_{OUT} = 4.8 \text{ mA}, V_{CC} = 5.5 \text{V}$	5.2	4.98	4.84	4.7	V
V _{OL}	Maximum LOW Level	$V_{IN} = V_{IH}$					
	Voltage	$ I_{OUT} = 20 \ \mu A$	0	0.1	0.1	0.1	V
		$ I_{OUT} = 4.0 \text{ mA}, V_{CC} = 4.5 \text{V}$	0.2	0.26	0.33	0.4	V
		$ I_{OUT} = 4.8 \text{ mA}, V_{CC} = 5.5 \text{V}$	0.2	0.26	0.33	0.4	V
I _{IN}	Maximum Input	V _{IN} = V _{CC} or GND,		±0.1	±1.0	±1.0	μA
	Current	V _{IH} or V _{IL}					
I _{CC}	Maximum Quiescent	$V_{IN} = V_{CC}$ or GND		2.0	20	40	μA
	Supply Current	$I_{OUT} = 0 \ \mu A$					
		V _{IN} = 2.4V or 0.5V (Note 4)		0.3	0.4	0.5	mA

Note 4: This is measured per input with all other inputs held at V_{CC} or ground.

	Extrical Characteristics = $t_F = 6 \text{ ns } C_L = 15 \text{ pF}, T_A = 25^{\circ}C \text{ (unless other states)}$	nerwise noted)			
Symbol	Parameter	Conditions	Тур	Guaranteed Limit	Units
t _{PLH} , t _{PHL}	Maximum Propagation Delay		10	18	ns
				1 1	

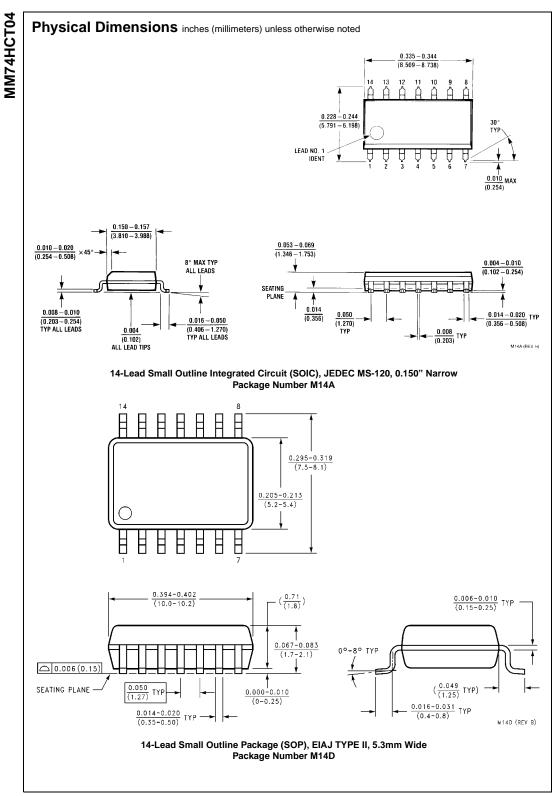
AC Electrical Characteristics

 V_{CC} = 5.0V ±10%, t_r = t_f = 6 ns, C_L = 50 pF (unless otherwise noted)

Symbol	Parameter	Conditions	T _A = 25°C		$T_{A} = -40 \text{ to } 85^{\circ}\text{C}$ $T_{A} = -55 \text{ to } 125^{\circ}\text{C}$		Units
	i arameter		Тур		Guaranteed L	imits	onna
t _{PLH} , t _{PHL}	Maximum Propagation Delay		14	20	25	30	ns
t _{THL} , t _{TLH}	Maximum Output Rise & Fall Time		8	15	19	22	ns
C _{PD}	Power Dissipation Capacitance	(Note 5)	20				pF
C _{IN}	Input Capacitance		5	10	10	10	pF

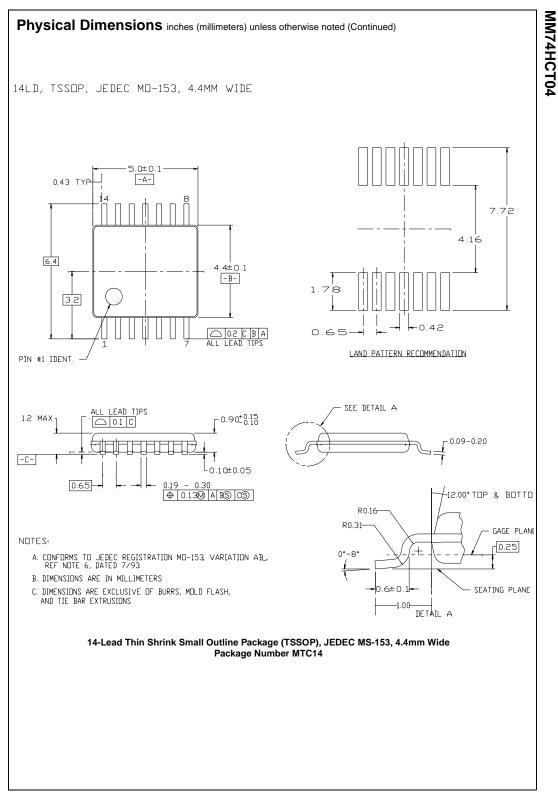
Note 5: C_{PD} determines the no load dynamic power consumption, $P_D = C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$, and the no load dynamic current consumption, $I_S = C_{PD} V_{CC} f + I_{CC}$.

www.fairchildsemi.com

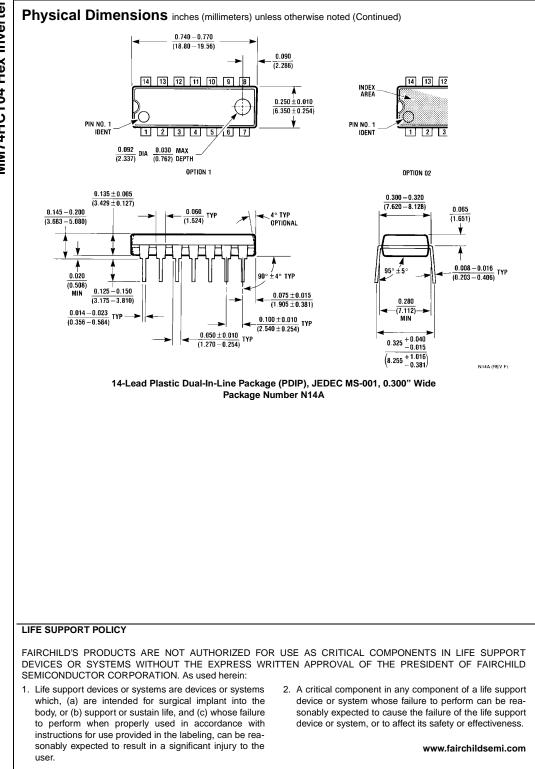


www.fairchildsemi.com

4



www.fairchildsemi.com



Fairchild does not assume any responsibility for use of any circuitry described, no circuit patent licenses are implied and Fairchild reserves the right at any time without notice to change said circuitry and specifications.